

**40V PNP MEDIUM POWER TRANSISTOR IN SOT23**

**Features**

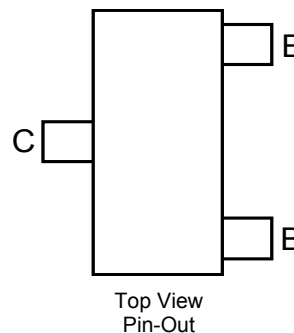
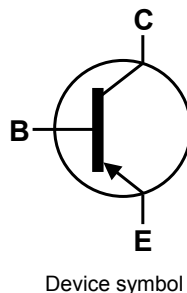
- $BV_{CEO} > -40V$
- $I_C = -1A$  High Continuous Current
- $I_{CM} = -2A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -500mV @ -1A$
- $R_{SAT} = 350m\Omega$  for a Low Equivalent On-resistance
- Complementary NPN type: ZXTN2040F
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound  
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per  
MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (approximate)

**Application**

- Power MOSFET gate driving
- Low loss power switching

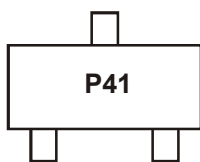


**Ordering Information** (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2041FTA	P41	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

**Marking Information**



P41 = Product Type Marking Code

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-1	A
Peak Pulse Current	I <sub>CM</sub>	-2	A
Base Current	I <sub>B</sub>	-200	mA
Peak Base Current	I <sub>BM</sub>	-1	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

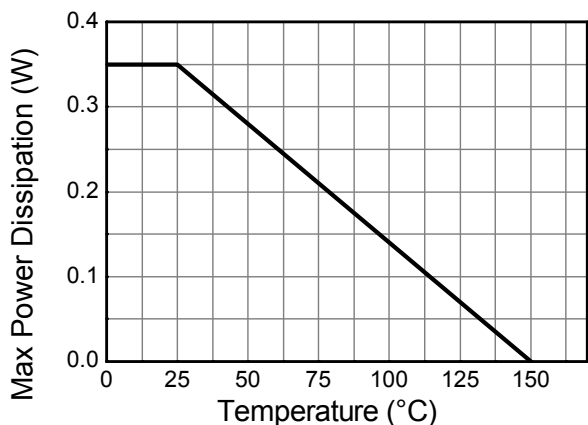
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	(Note 5)	310
		(Note 6)	350
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	(Note 5)	403
		(Note 6)	357
Thermal Resistance, Junction to Leads	R <sub>θJL</sub>	350	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

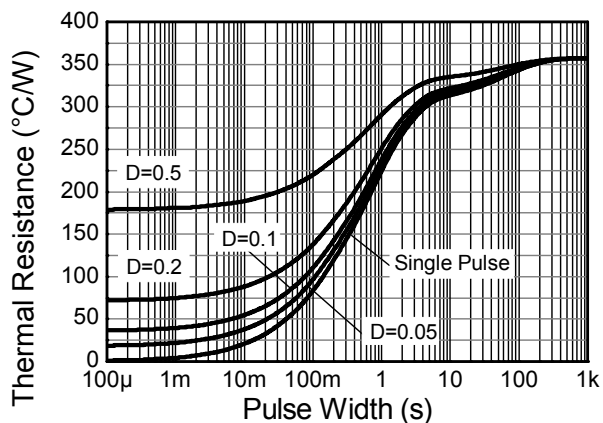
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as note (5), except the device is mounted on 15 mm x 15mm 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the leads).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

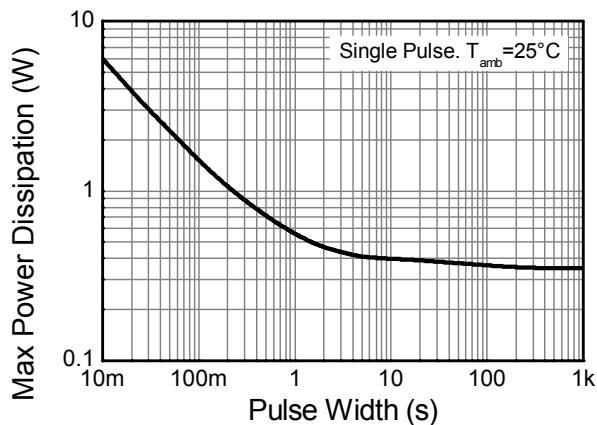
**Thermal Characteristics and Derating Information**



**Derating Curve**



**Transient Thermal Impedance**



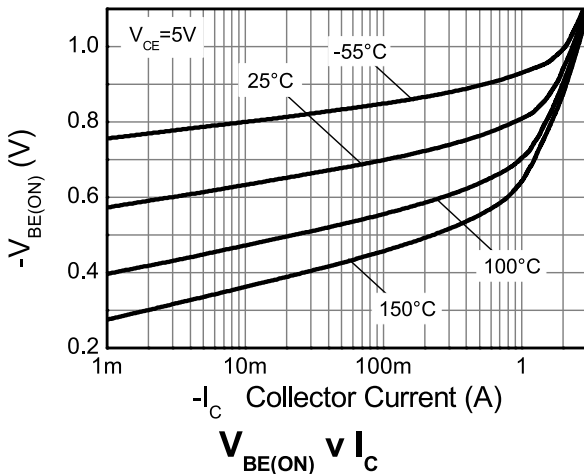
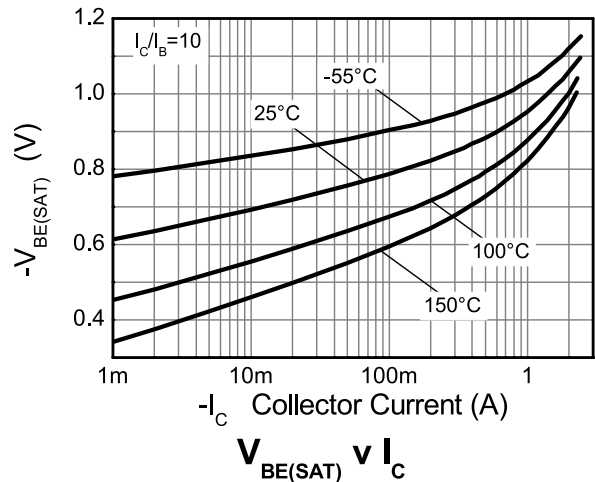
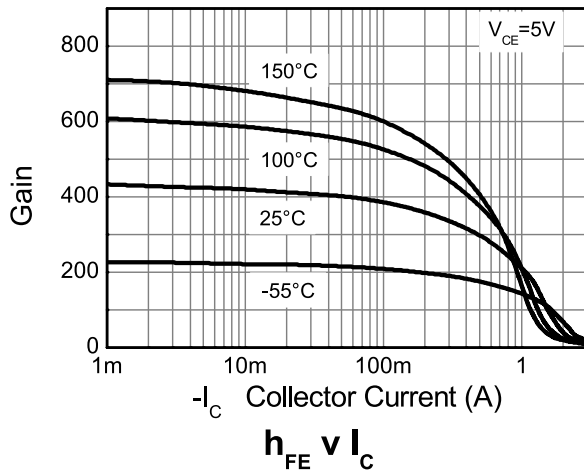
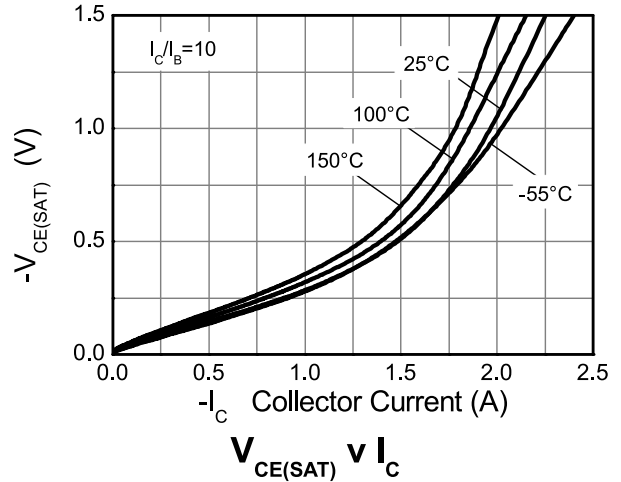
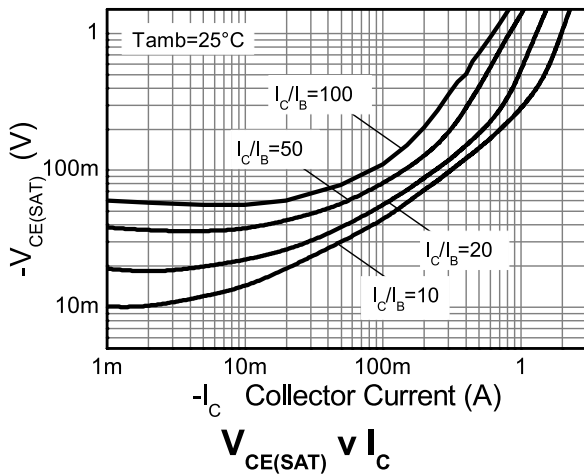
**Pulse Power Dissipation**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-40	-	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-40	-	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CB0</sub>	-	-	-100	nA	V <sub>CB</sub> = -30V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	nA	V <sub>EB</sub> = -5.6V
Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CE</sub> = -30V
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	300	-	-	-	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V
		300	-	800		I <sub>C</sub> = -100mA, V <sub>CE</sub> = -5V
		250	-	-		I <sub>C</sub> = -500mA, V <sub>CE</sub> = -5V
		160	-	-		I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V
		30	-	-		I <sub>C</sub> = -2A, V <sub>CE</sub> = -5V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-	-200	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -1mA
		-	-	-350		I <sub>C</sub> = -500mA, I <sub>B</sub> = -20mA
		-	-	-500		I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-	-1.1	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	-	-	-1.0	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V
Transitional Frequency	f <sub>T</sub>	150	300	-	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V, f = 100MHz
Output capacitance	C <sub>obo</sub>	-	-	10	pF	V <sub>CB</sub> = -10V, f = 1MHz,
Switching Time	Delay Time	t <sub>(d)</sub>	-	34.9	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -500mA, I <sub>B1</sub> = -I <sub>B2</sub> = 25mA
	Rise Time	t <sub>(r)</sub>	-	19.2		
	Storage Time	t <sub>(s)</sub>	-	249		
	Fall Time	t <sub>(f)</sub>	-	62		

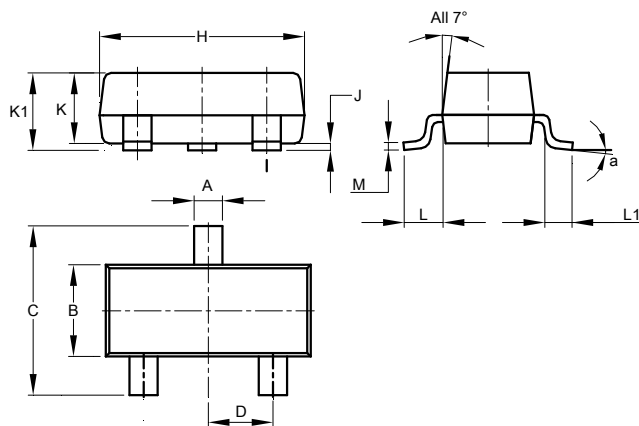
Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

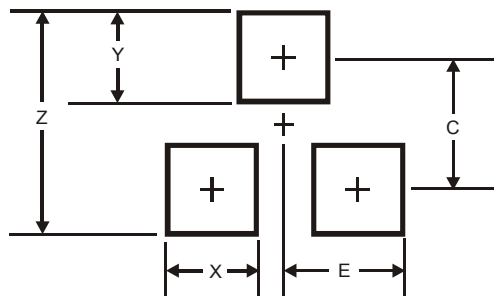
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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